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SEMICONDUCTOR



ESD



TVS



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MOV



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PLED

AZ1117H-XXXTRE1-MS

Product specification

概述

AZ1117H-XXXTRE1-MS 是一款低压差的线性稳压器。


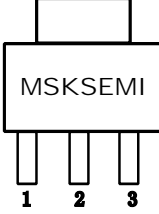






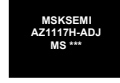
特点

- 包括三端可调输出和固定电压输出版本（固定电压包括 1.2V, 1.5V, 1.8V, 2.5V, 3.3V, 5V 等，其他电压规格可根据用户定制）
- 最大输出电流为 1A
- 输出电压精度高达 ±2%
- 稳定工作电压范围为高达 12V
- 电压线性度为 0.2%
- 负载线性度为 0.4%
- 环境温度：T_A 的范围是 -20°C ~ 125°C

用途

- 计算机主板、显卡
- LCD 监视器及 LCD TV
- DVD 解码板
- ADSL 等设备
- 开关电源的后级稳压

包装和订单信息

产品编号	输出电压	封装		引脚排列	管体标记	最小包装 (PCS)
AZ1117H-1.2TRE1-MS	1.2V	SOT-223				2500
AZ1117H-1.5TRE1-MS	1.5V					2500
AZ1117H-1.8TRE1-MS	1.8V					2500
AZ1117H-2.5TRE1-MS	2.5V					2500
AZ1117H-3.3TRE1-MS	3.3V					2500
AZ1117H-5.0TRE1-MS	5.0V					2500
AZ1117H-ADJTRE1-MS	ADJ					2500

注：***代表内部生产批号

引脚定义

引脚号	符号	定义
1	GND	接地脚
2	Vout	输出端
3	Vin	输入端

固定电
压型

引脚号	符号	定义
1	Adj.	可调端
2	Vout	输出端
3	Vin	输入端

可调电
压型

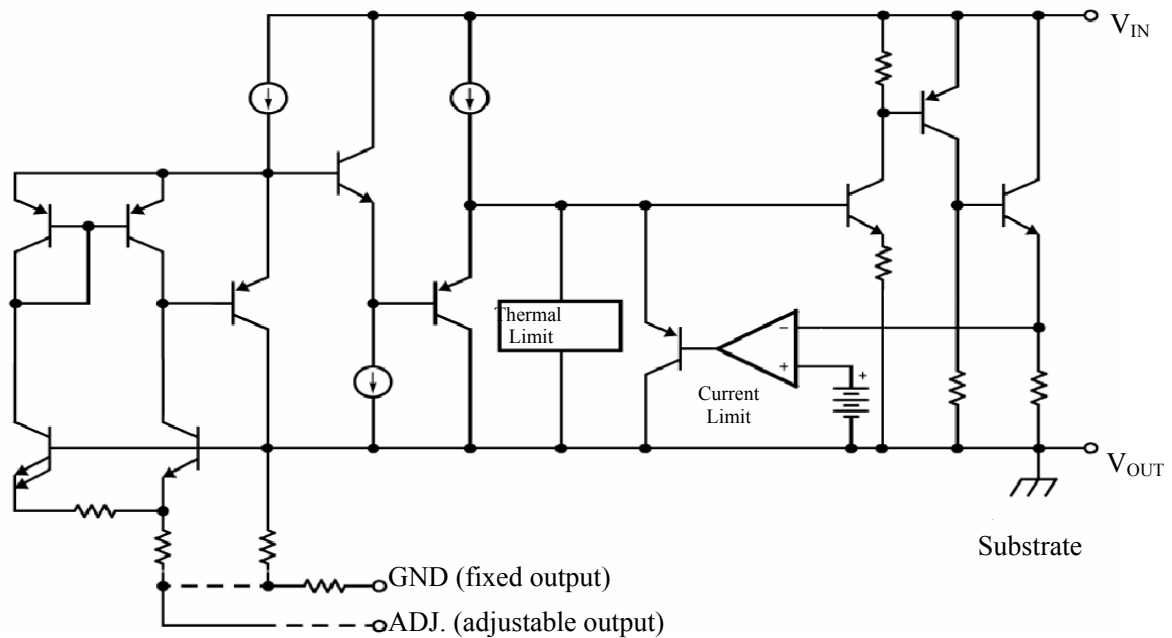
极限值

参数名称	符号	数值	单位
最大输入电压	V _{in}	18	V
最大结温	T _J	125	°C
最大环境温度	T _A	125	°C
贮存温度	T _s	-65~+150	°C
焊接温度和时间		300°C,10S	

推荐工作条件

名称	最小	推荐	最大	单位
输入电压范围			15	V
工作环境温度	0		125	°C

功能图



主要参数和工作特性

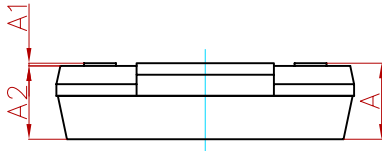
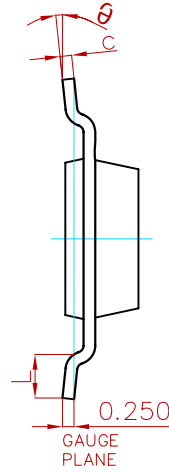
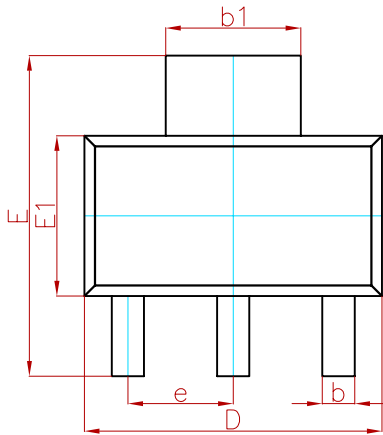
Tj=25°C

参数	参数说明	条件	最小值	典型值	最大值	单位
Vref	参考电压	I _{out} =10mA, V _{in} -V _{out} =2V 10mA ≤ I _{out} ≤ 1A, 1.5V ≤ V _{in} -V _{out} ≤ 10V	1.225	1.25	1.275	V
Vout	输出电压	AZ1117H-1.2TRE1-MS 10mA ≤ I _{out} ≤ 1A, 2.7V ≤ V _{in} ≤ 10V	1.176	1.2	1.224	V
		AZ1117H-1.5TRE1-MS 10mA ≤ I _{out} ≤ 1A, 3.0V ≤ V _{in} ≤ 10V	1.47	1.5	1.53	V
		AZ1117H-1.8TRE1-MS 10mA ≤ I _{out} ≤ 1A, 3.25V ≤ V _{in} ≤ 10V	1.764	1.80	1.836	V
		AZ1117H-2.5TRE1-MS 10mA ≤ I _{out} ≤ 1A, 3.9 V ≤ V _{in} ≤ 10V	2.45	2.50	2.55	V
		AZ1117H-3.3TRE1-MS 10mA ≤ I _{out} ≤ 1A, 5.3 V ≤ V _{in} ≤ 12V	3.235	3.3	3.365	V
		AZ1117H-5.0TRE1-MS 10mA ≤ I _{out} ≤ 1A, 6.5V ≤ V _{in} ≤ 12V	4.9	5	5.1	V
ΔVout	电压线性度	AZ1117H-ADJTRE1-MS I _{out} =10mA, V ≤ V _{in} -V _{out} ≤ 10V		5	18	mV
		AZ1117H-1.2TRE1-MS I _{out} =10mA, 2.7V ≤ V _{in} ≤ 10V		5	18	mV
		AZ1117H-1.5TRE1-MS I _{out} =10mA, 2.75V ≤ V _{in} ≤ 10V		5	18	mV
		AZ1117H-1.8TRE1-MS I _{out} =10mA, 3.25V ≤ V _{in} ≤ 10V		5	18	mV
		AZ1117H-2.5TRE1-MS I _{out} =10mA, 3.9V ≤ V _{in} ≤ 10V		5	18	mV
		AZ1117H-3.3TRE1-MS I _{out} =10mA, 5.3 V ≤ V _{in} ≤ 12V		9	18	mV
ΔVout	负载线性度	AZ1117H-ADJTRE1-MS V _{in} = 3.25V, 10mA ≤ I _{out} ≤ 1A		9	18	mV
		AZ1117H-1.2TRE1-MS V _{in} = 2.7V, 10mA ≤ I _{out} ≤ 1A		9	18	mV
		AZ1117H-1.5TRE1-MS V _{in} = 3.25V, 10mA ≤ I _{out} ≤ 1A		9	18	mV

主要参数和工作特性

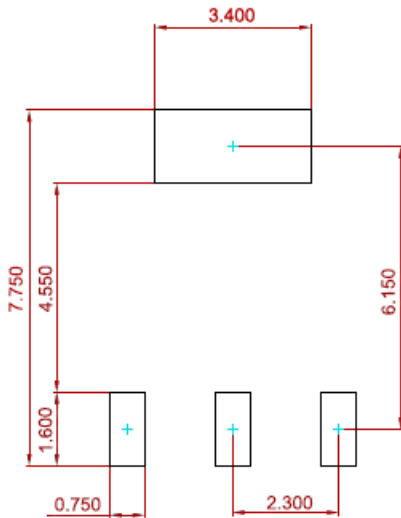
		AZ1117H-1.8TRE1-MS Vin = 3.25V, 10mA ≤ Iout ≤ 1A		10	18	mV
		AZ1117H-2.5TRE1-MS Vin = 4.5 V, 10mA ≤ Iout ≤ 1A		10	18	mV
		AZ1117H-3.3TRE1-MS Vin = 5.3V, 0 ≤ Iout ≤ 1A		12	20	mV
		AZ1117H-5.0TRE1-MS Vin = 6.5V, 0 ≤ Iout ≤ 1A		12	20	mV
Vin-Vout	最小输入输出电压差	ΔVout, ΔVref, =1%, Iout=1A			1.4	V
Ilimit	最小负载电流	AZ1117H-ADJTRE1-MS			10	mA
Iq	静态电流	AZ1117H-ADJTRE1-MS, Vin = 4.0V			12	mA
		AZ1117H-1.2TRE1-MS, Vin = 4.8V			12	mA
		AZ1117H-1.5TRE1-MS, Vin = 4.8V			12	mA
		AZ1117H-1.8TRE1-MS, Vin = 4.8V			12	mA
		AZ1117H-2.5TRE1-MS, Vin = 4.8V			12	mA
		AZ1117H-3.3TRE1-MS, Vin = 4.8V			12	mA
		AZ1117H-5.0TRE1-MS, Vin = 4.8V			12	mA

封装信息



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	—	1.800	—	0.071
A1	0.020	0.100	0.001	0.004
A2	1.500	1.700	0.059	0.067
b	0.660	0.840	0.026	0.033
b_1	2.900	3.100	0.114	0.122
c	0.230	0.350	0.009	0.014
D	6.300	6.700	0.248	0.264
E	6.700	7.300	0.264	0.287
E1	3.300	3.700	0.130	0.146
e	2.300(BSC)		0.091(BSC)	
L	0.750	—	0.030	—
θ	0°	10°	0°	10°

焊盘布局建议



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: ± 0.050 mm.
3. The pad layout is for reference purposes only.

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